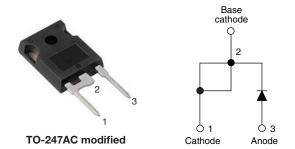


# VS-40EPS...PbF Series, VS-40EPS...-M3 Series

Vishay Semiconductors

# High Voltage, Input Rectifier Diode, 40 A



PRODUCT SUMMARY	
Package	TO-247AC modified (2 pins)
I <sub>F(AV)</sub>	40 A
V <sub>R</sub>	800 V to 1200 V
V <sub>F</sub> at I <sub>F</sub>	1.1 V
I <sub>FSM</sub>	475 A
T <sub>J</sub> max.	150 °C
Diode variation	Single die

#### **FEATURES**

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- · Designed and qualified according to JEDEC®-JESD47
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912







#### **APPLICATIONS**

- · Input rectification
- · Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

#### **DESCRIPTION**

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS VALUES								
I <sub>F(AV)</sub>	Sinusoidal waveform	40	Α						
V <sub>RRM</sub>	Range	800/1200	V						
I <sub>FSM</sub>		475	Α						
V <sub>F</sub>	40 A, T <sub>J</sub> = 25 °C	1.1	V						
T <sub>J</sub>		-40 to 150	°C						

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-40EPS08PbF, VS-40EPS08-M3	800	900	1						
VS-40EPS12PbF, VS-40EPS12-M3	1200	1300	ı						

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS VALUE							
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 105$ °C, 180° conduction half sine wave	40					
Maximum peak one cycle	I <sub>FSM</sub>	10 ms sine pulse, rated V <sub>RRM</sub> applied 400		Α				
non-repetitive surge current		10 ms sine pulse, no voltage reapplied	475					
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	800	A <sup>2</sup> s				
iviaximum i-t for fusing	I-L	10 ms sine pulse, no voltage reapplied	1131 A <sup>2</sup> S					
Maximum I²√t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	11 310	A <sup>2</sup> √s				



# Vishay Semiconductors

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CON	IDITIONS	VALUES	UNITS				
Maximum famuard valtage drag	V	20 A, T <sub>J</sub> = 25 °C		1.0	V				
Maximum forward voltage drop	V <sub>FM</sub>	40 A, T <sub>J</sub> = 25 °C		1.1					
Forward slope resistance	r <sub>t</sub>	T 150 °C		7.16	mΩ				
Threshold voltage	V <sub>F(TO)</sub>	T <sub>J</sub> = 150 °C		0.74	V				
Maximum varyayaa laakaga ayyyyant		T <sub>J</sub> = 25 °C	V Dated V	0.1	A				
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	$V_R = Rated V_{RRM}$	1.0	mA				

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storrage temperature range	Maximum junction and storrage temperature range			-40 to 150	°C			
Maximum thermal resistance, junction to case		$R_{\text{thJC}}$	DC operation 0.6					
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W			
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	0.2				
Approximate weight				6	g			
Approximate weight				0.21	oz.			
Mounting torque -	minimum			6 (5)	kgf · cm			
Mounting torque =	maximum			12 (10)	(lbf · in)			
Madding dayler			Coop atula TO 247AC modified (JEDEC)	40EPS08				
Marking device			Case style TO-247AC modified (JEDEC)	40EPS12				

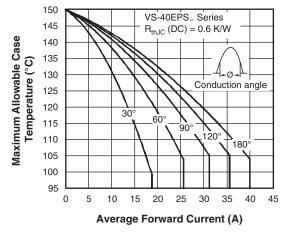


Fig. 1 - Current Rating Characteristics

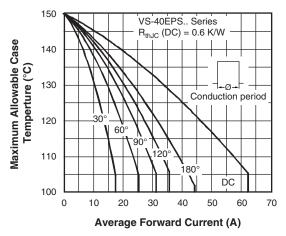


Fig. 2 - Current Rating Characteristics

www.vishay.com

## Vishay Semiconductors

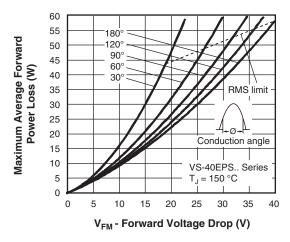


Fig. 3 - Forward Power Loss Characteristics

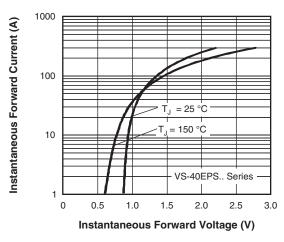


Fig. 5 - Forward Voltage Drop Chacteristics

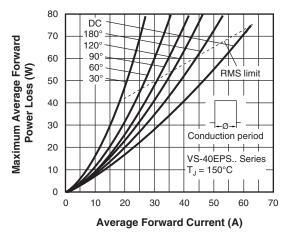


Fig. 4 - Forward Power Loss Characteristics

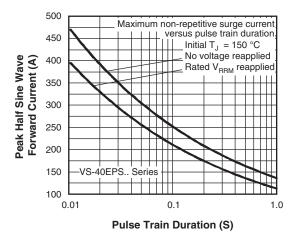


Fig. 6 - Maximum Non-Repetitive Surge Current

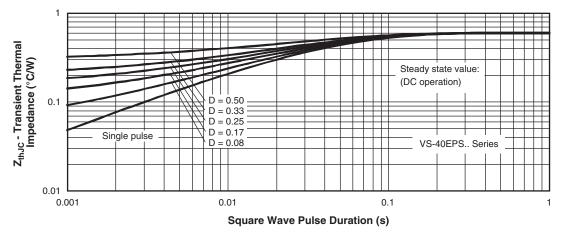


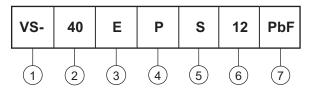
Fig. 7 - Thermal Impedance ZthJC Characteristics

# VS-40EPS...PbF Series, VS-40EPS...-M3 Series

Vishay Semiconductors

#### **ORDERING INFORMATION TABLE**

**Device code** 



1 - Vishay Semiconductors product

2 - Current rating (40 = 40 A)

Circuit configuration:

E = Single diode

4 - Package:

P = TO-247AC modified

5 - Type of silicon:

S = Standard recovery rectifier

08 = 800 V

Voltage rating

12 = 1200 V

7 - Environmental digit:

PbF = Lead (Pb)-free and RoHS compliant

-M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

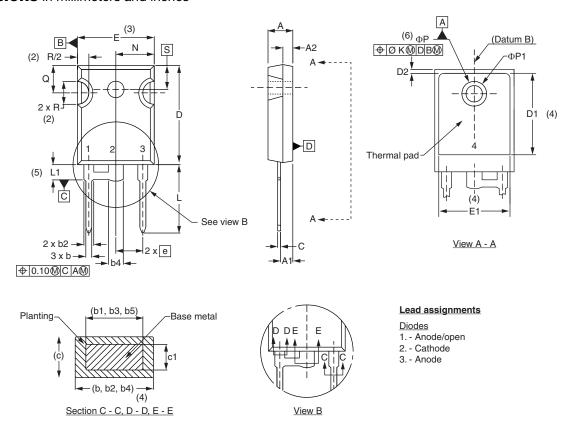
ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-40EPS08PbF	25	500	Antistatic plastic tubes					
VS-40EPS08-M3	25	500	Antistatic plastic tubes					
VS-40EPS12PbF	25	500	Antistatic plastic tubes					
VS-40EPS12-M3	25	500	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS							
Dimensions		www.vishay.com/doc?95253					
Part marking information	TO-247AC modified PbF	www.vishay.com/doc?95255					
	TO-247AC modified -M3	www.vishay.com/doc?95442					



## Vishay Semiconductors

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.37	0.065	0.094	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.86	0.015	0.034	
c1	0.38	0.76	0.015	0.030	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.72	-	0.540	1	
е	5.46	BSC	0.215	BSC	
ΦК	2.54		0.0	0.010	
L	14.20	16.10	0.559	0.634	
L1	3.71	4.29	0.146	0.169	
N	7.62	BSC	0.3		
ΦР	3.56	3.66	0.14	0.144	
ФР1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52 5.49		1.78	0.216	
S	5.51	BSC	0.217	BSC	

#### Notes

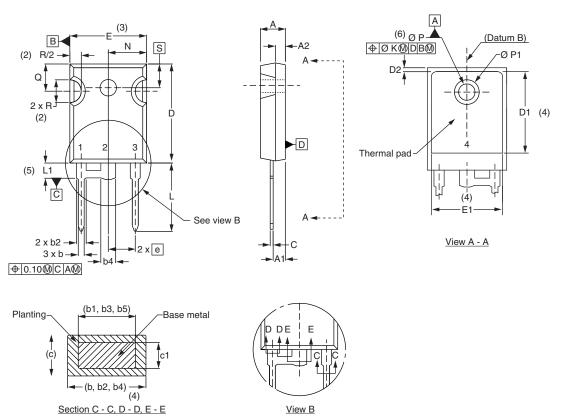
- (1) Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6)  $\Phi P$  to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC outline TO-247 with exception of dimension c



## Vishay Semiconductors

### TO-247 modified

#### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIM	MILLIMETERS		HES	NOTES	SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STMBUL	MIN.	MAX.	MIN.	MAX.	NOTES	STWIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209		D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102		E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054		E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055		е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053		ØK	0.2	254	0.0	)10	
b2	1.65	2.39	0.065	0.094		L	14.20	16.10	0.559	0.634	
b3	1.65	2.33	0.065	0.092		L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135		N	7.62	BSC	0	.3	
b5	2.59	3.38	0.102	0.133		ØΡ	3.56	3.66	0.14	0.144	
С	0.38	0.89	0.015	0.035		Ø P1	-	7.39	-	0.291	
c1	0.38	0.84	0.015	0.033		Q	5.31	5.69	0.209	0.224	
D	19.71	20.70	0.776	0.815	3	R	4.52	5.49	0.178	0.216	
D1	13.08	-	0.515	-	4	S	5.51	BSC	0.217	' BSC	

#### Notes

- (1) Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
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- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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